



InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

Typical Applications

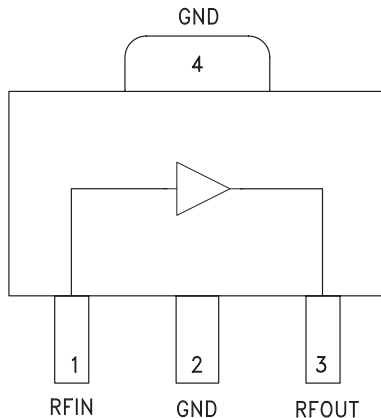
The HMC452ST89 / HMC452ST89E is ideal for applications requiring a high dynamic range amplifier:

- GSM, GPRS & EDGE
- CDMA & W-CDMA
- CATV/Cable Modem
- Fixed Wireless

Features

Output IP3: +49 dBm
 21 dB Gain @ 400 MHz
 9 dB Gain @ 2100 MHz
 50% PAE @ +31 dBm Pout
 +25 dBm CDMA2000 Channel Power
 @ -45 dBc ACP
 Included in the HMC-DK002 Designer's Kit

Functional Diagram



General Description

The HMC452ST89 & HMC452ST89E are high dynamic range GaAs InGaP HBT 1 Watt MMIC power amplifiers operating from 0.4 to 2.2 GHz and packaged in industry standard SOT89 packages. Utilizing a minimum number of external components and a single +5V supply, the amplifier output IP3 can be optimized to +45 dBm at 0.4 GHz or +49 dBm at 2.1 GHz. The high output IP3 and PAE make the HMC452ST89 & HMC452ST89E ideal power amplifiers for Cellular/PCS/3G and Fixed Wireless applications.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_S = +5\text{V}$ [1]

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	400 - 410			450 - 496			810 - 960			1710 - 1990			2010 - 2170			MHz
Gain	19	21		18	20		13.5	15.5		7	9.5		7	9		dB
Gain Variation Over Temperature		0.012	0.02		0.012	0.02		0.012	0.02		0.012	0.02		0.012	0.02	dB / °C
Input Return Loss		22			16			13			13			20		dB
Output Return Loss		11			11			14			15			15		dB
Output Power for 1dB Compression (P1dB)	27	30		27	30		27.5	30.5		28	31		28.5	31.5		dBm
Saturated Output Power (Psat)		30.5			30.5			31.5			31.5			32		dBm
Output Third Order Intercept (IP3) [2]	42	45		42	45		44	47		45	48		46	49		dBm
Noise Figure		6.5			7			6.5			6.5			6.5		dB
Supply Current (Icq)		510			510			510			510			510		mA

[1] Specifications and data reflect HMC452ST89 measured using the respective application circuits for each designated frequency band found herein. Contact the HMC Applications Group for assistance in optimizing performance for your application.

[2] Two-tone input power of 0 dBm per tone, 1 MHz spacing.

HMC452ST89* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- HMC452ST89 Evaluation Board.

DOCUMENTATION

Application Notes

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers
- Broadband Biasing of Amplifiers General Application Note
- MMIC Amplifier Biasing Procedure Application Note
- Thermal Management for Surface Mount Components General Application Note

Data Sheet

- HMC452ST89 Data Sheet

TOOLS AND SIMULATIONS

- HMC452ST89 S-Parameters

REFERENCE MATERIALS

Quality Documentation

- Package/Assembly Qualification Test Report: 3 Lead Plastic SOT89 Package (QTR: 10002 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-B (QTR: 2013-00229)

DESIGN RESOURCES

- HMC452ST89 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC452ST89 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

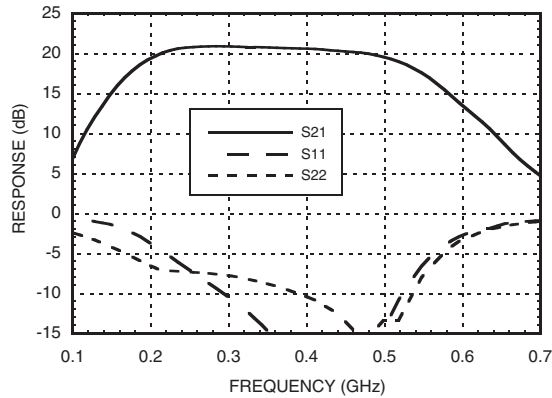
Submit feedback for this data sheet.



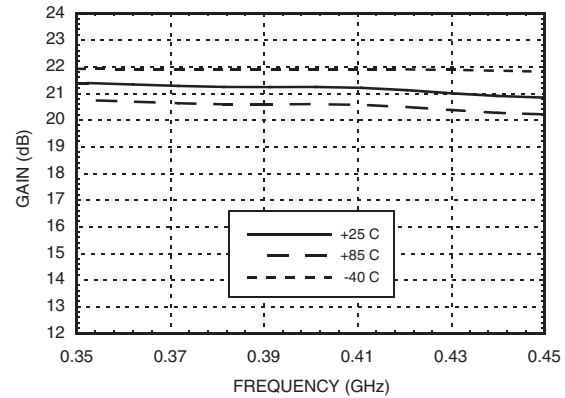
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

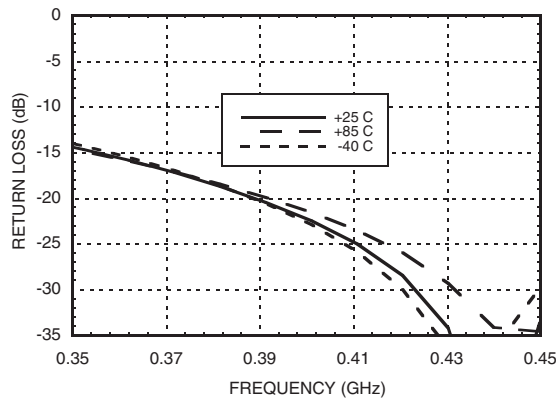
Broadband Gain & Return Loss @ 400 MHz



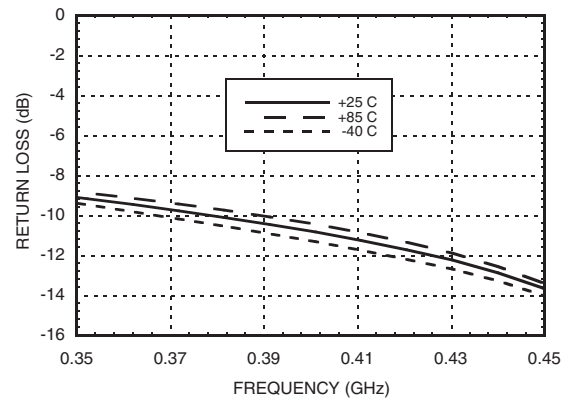
Gain vs. Temperature @ 400 MHz



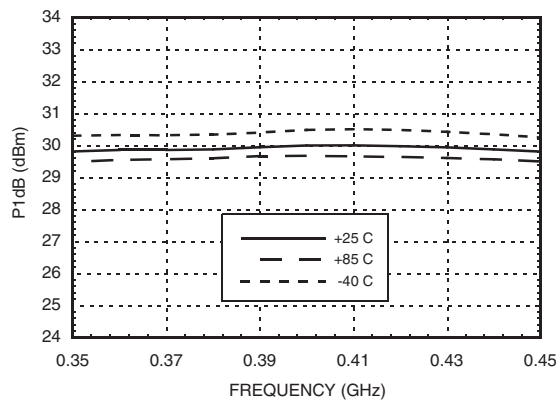
Input Return Loss vs. Temperature @ 400 MHz



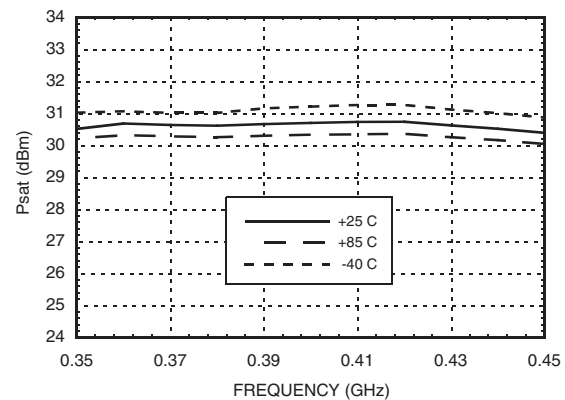
Output Return Loss vs. Temperature @ 400 MHz

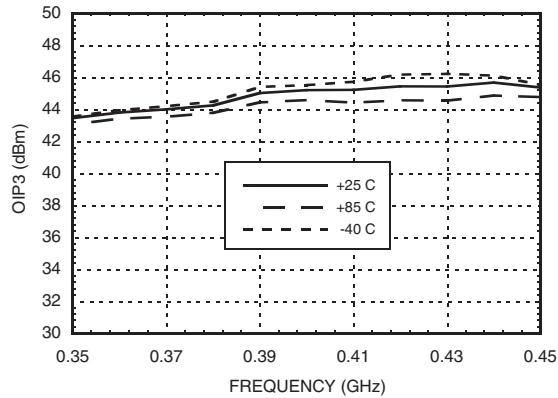
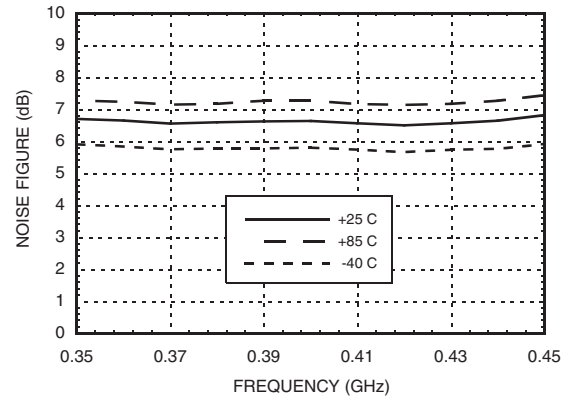
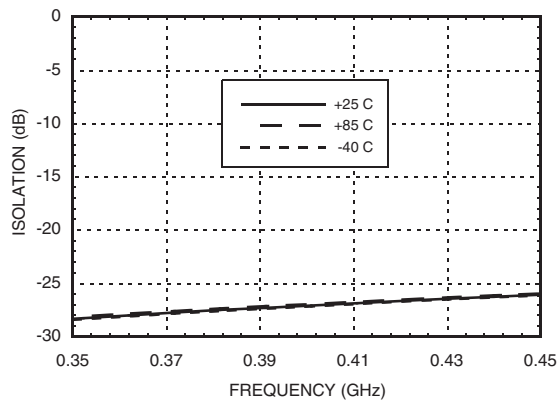
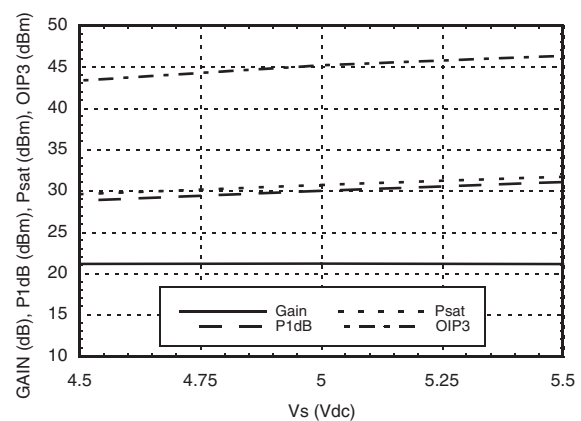
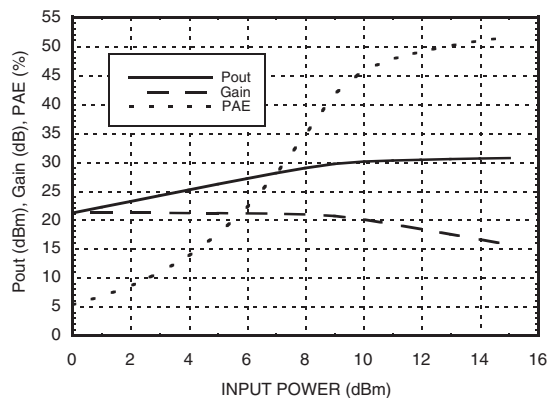
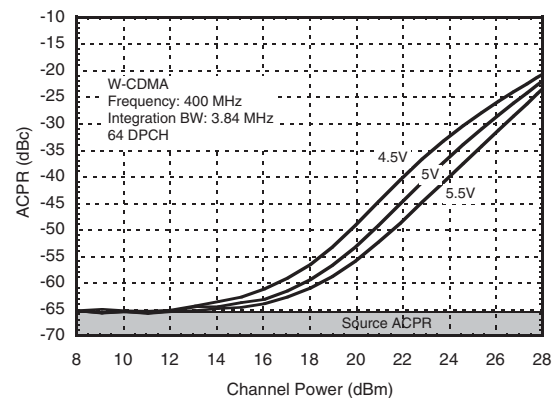


P1dB vs. Temperature @ 400 MHz



Psat vs. Temperature @ 400 MHz



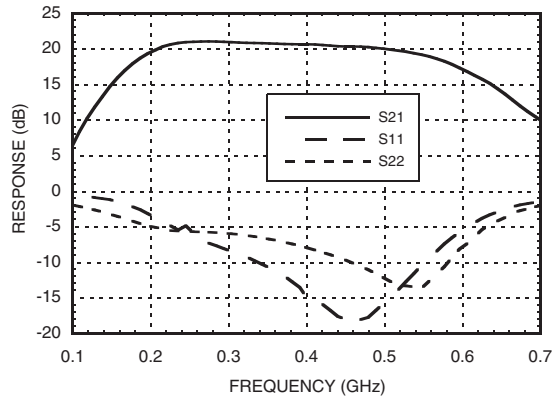
Output IP3 vs. Temperature @ 400 MHz

**Noise Figure
vs. Temperature @ 400 MHz**

**Reverse Isolation
vs. Temperature @ 400 MHz**

**Gain, Power & IP3
vs. Supply Voltage @ 400 MHz**

Power Compression @ 400 MHz

**ACPR vs. Supply Voltage @ 400 MHz
W-CDMA, 64 DPCH**




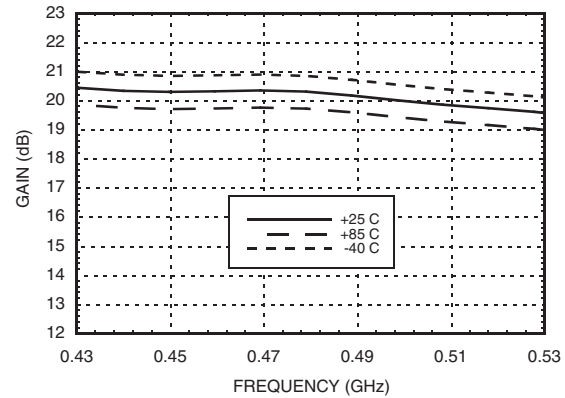
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

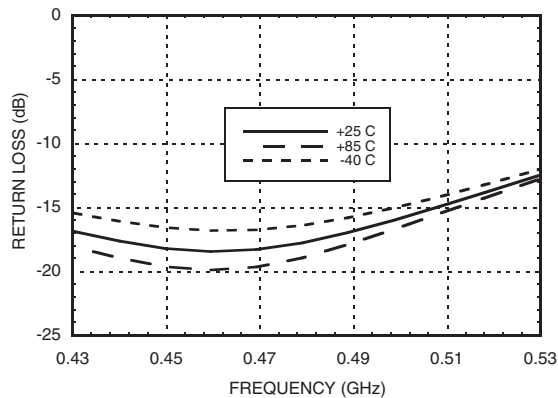
Broadband Gain & Return Loss @ 470 MHz



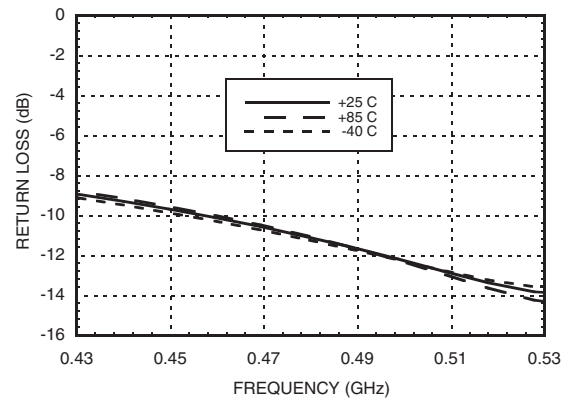
Gain vs. Temperature @ 470 MHz



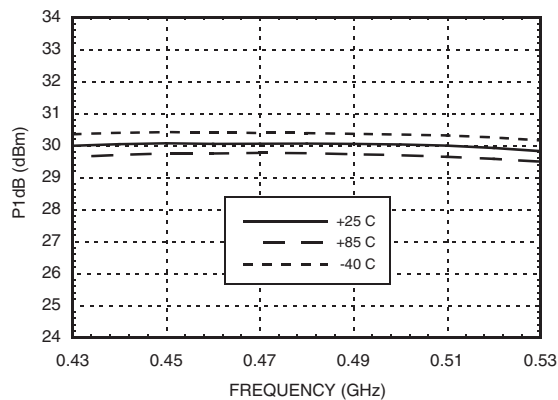
Input Return Loss vs. Temperature @ 470 MHz



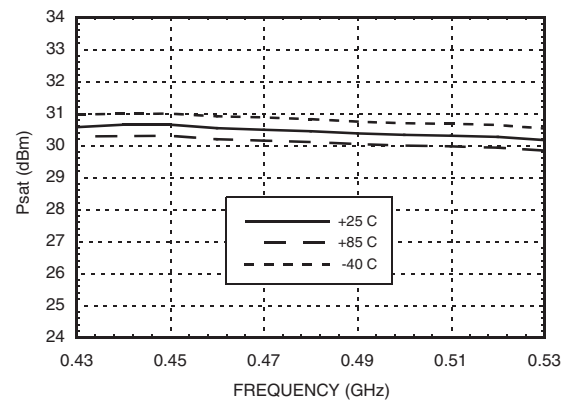
Output Return Loss vs. Temperature @ 470 MHz



P1dB vs. Temperature @ 470 MHz



Psat vs. Temperature @ 470 MHz

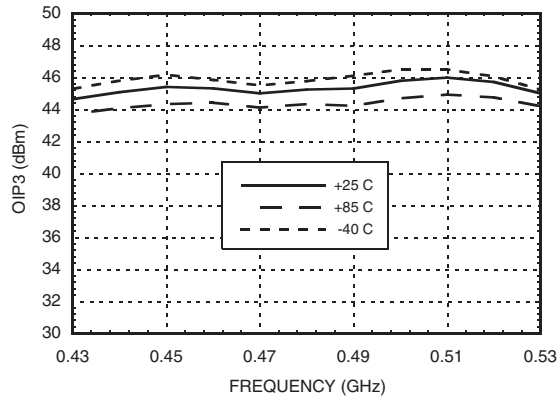




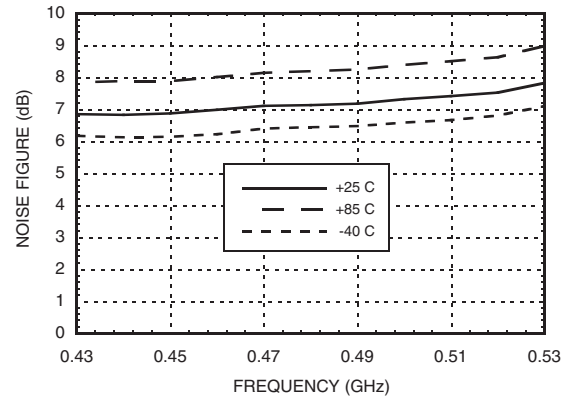
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InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

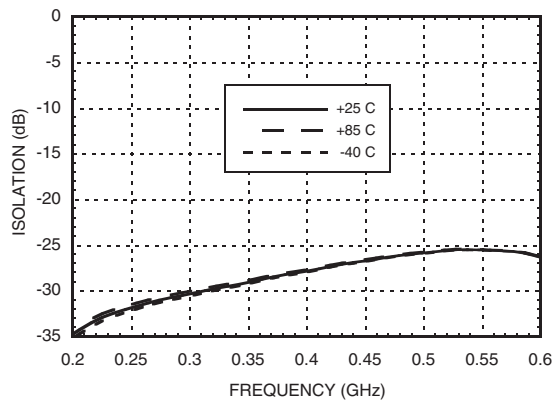
Output IP3 vs. Temperature @ 470 MHz



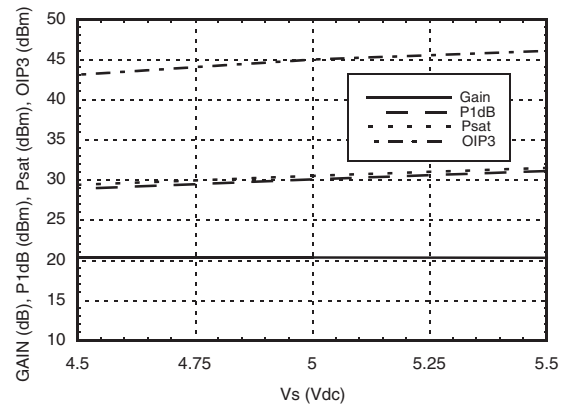
**Noise Figure
vs. Temperature @ 470 MHz**



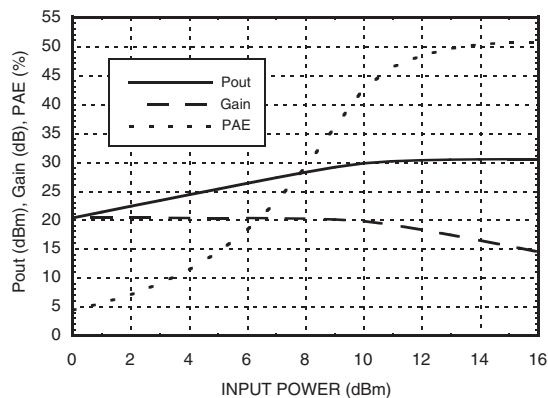
**Reverse Isolation
vs. Temperature @ 470 MHz**



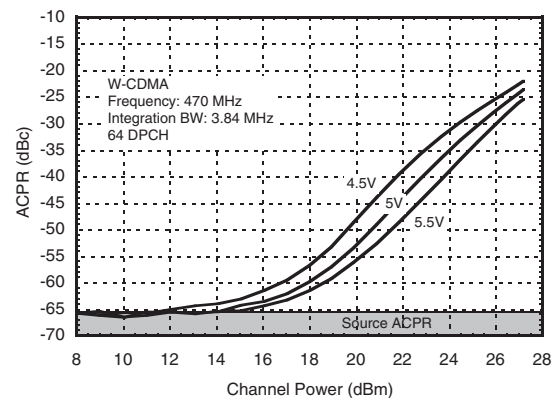
**Gain, Power & IP3
vs. Supply Voltage @ 470 MHz**



Power Compression @ 470 MHz

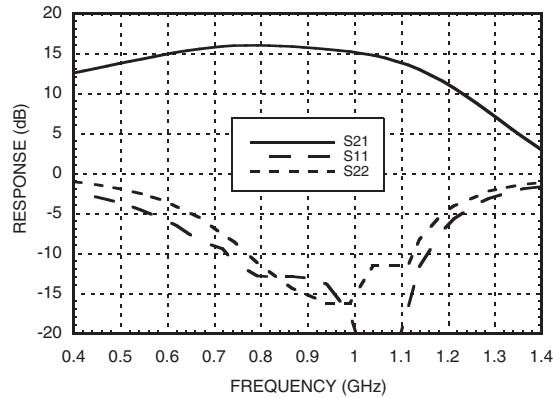


**ACPR vs. Supply Voltage @ 470 MHz
W-CDMA, 64 DPCH**

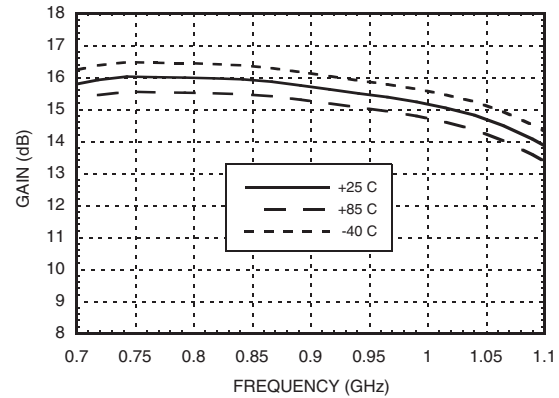




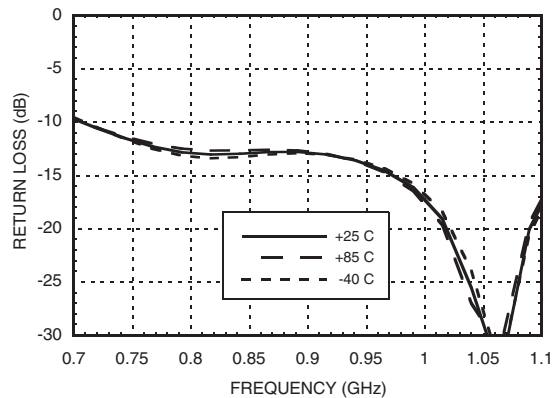
**Broadband Gain
& Return Loss @ 900 MHz**



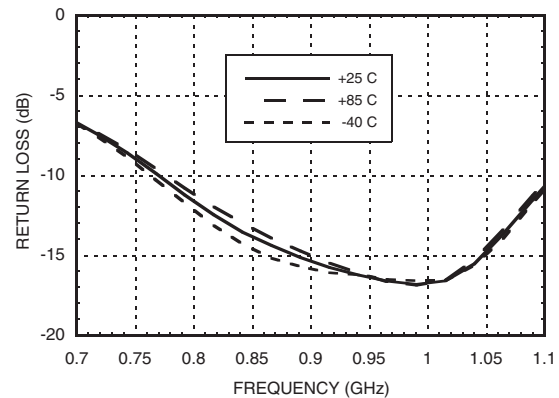
Gain vs. Temperature @ 900 MHz



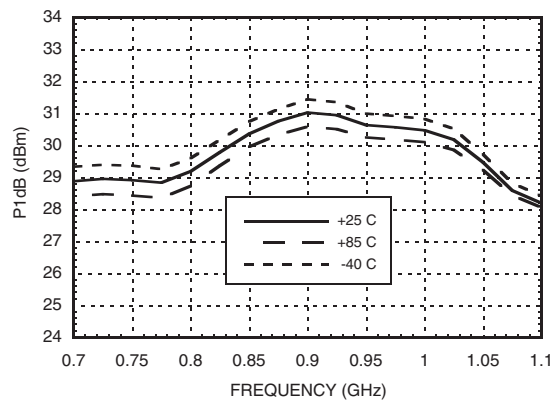
**Input Return Loss
vs. Temperature @ 900 MHz**



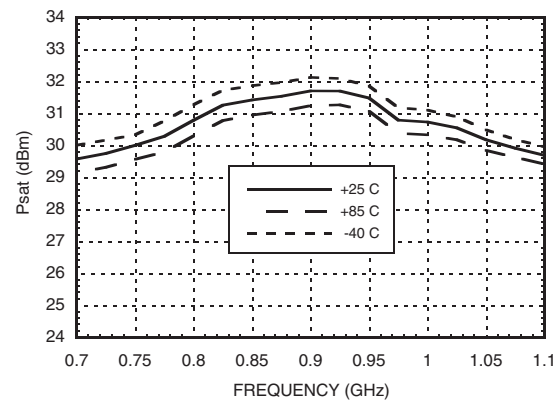
**Output Return Loss
vs. Temperature @ 900 MHz**



P1dB vs. Temperature @ 900 MHz



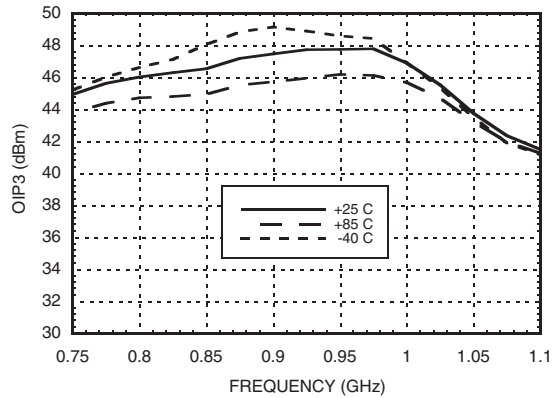
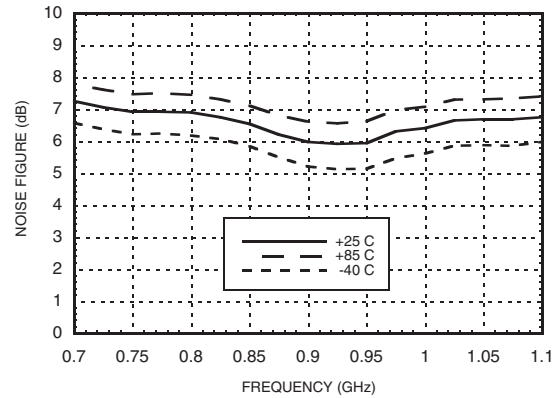
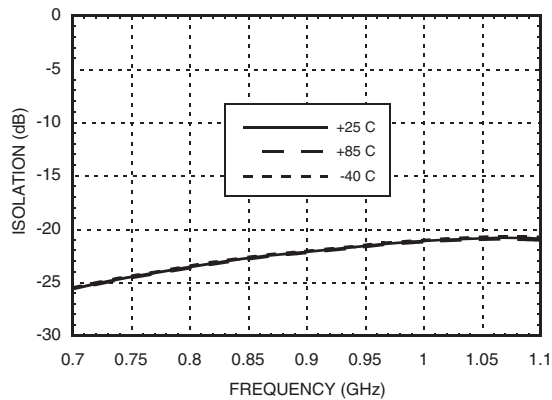
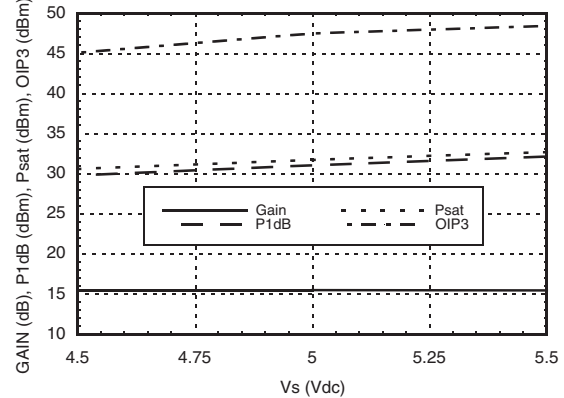
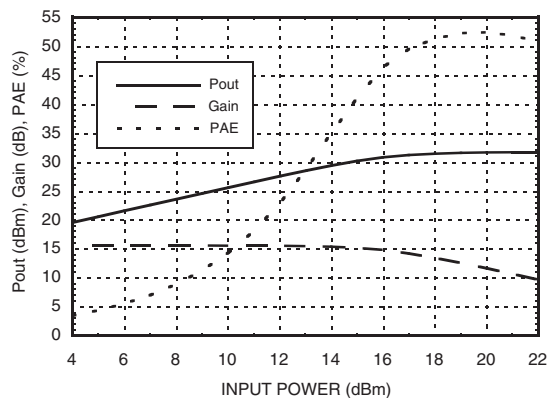
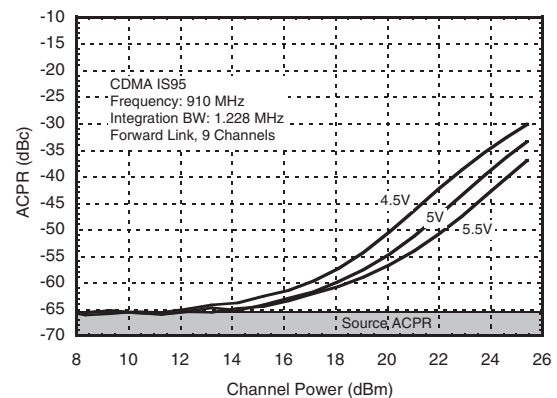
Psat vs. Temperature @ 900 MHz





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InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

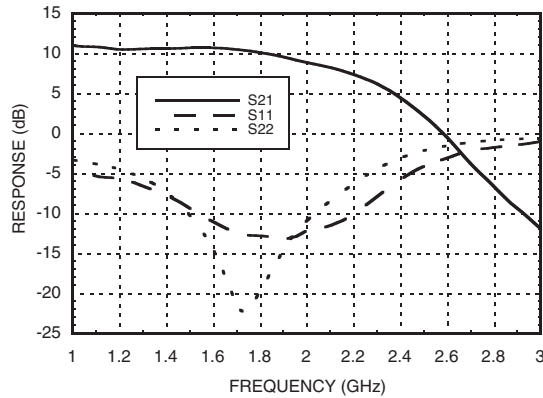
Output IP3 vs. Temperature @ 900 MHz

**Noise Figure
vs. Temperature @ 900 MHz**

**Reverse Isolation
vs. Temperature @ 900 MHz**

**Gain, Power & IP3
vs. Supply Voltage @ 900 MHz**

Power Compression @ 900 MHz

**ACPR vs. Supply Voltage @ 910 MHz
CDMA IS95, 9 Channels Forward**




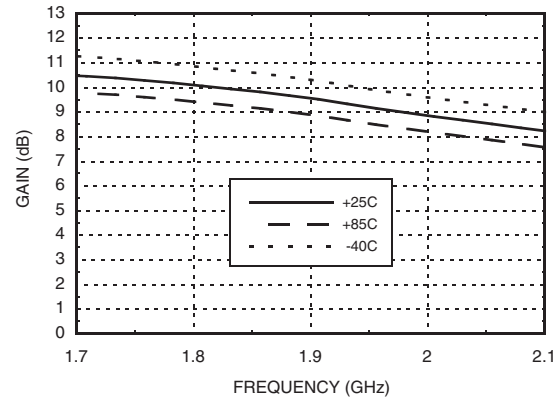
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

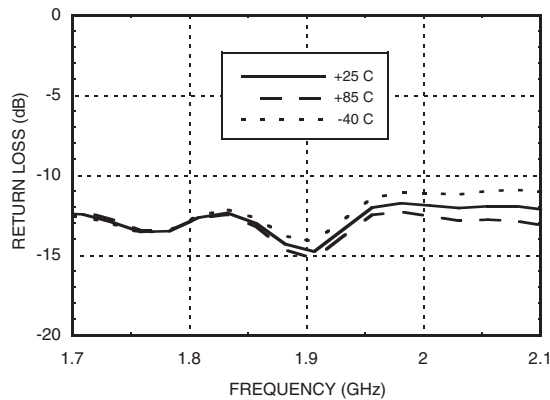
Broadband Gain & Return Loss @ 1900 MHz



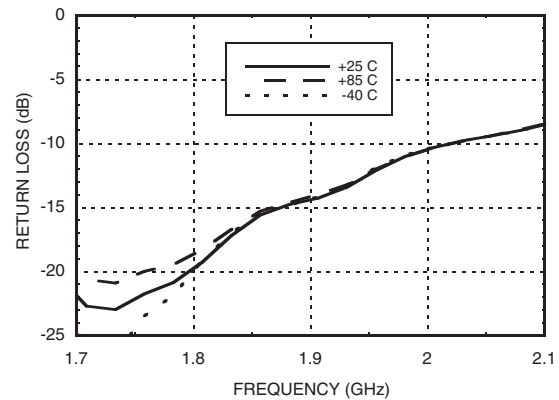
Gain vs. Temperature @ 1900 MHz



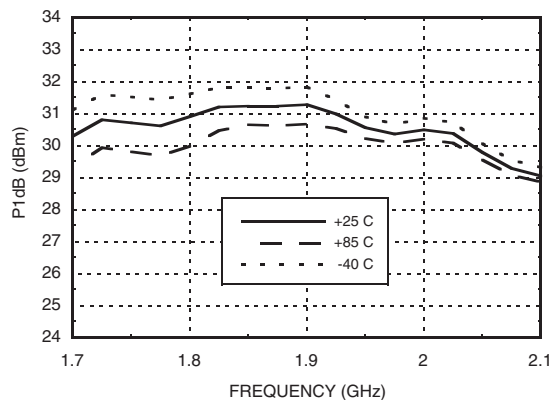
Input Return Loss vs. Temperature @ 1900 MHz



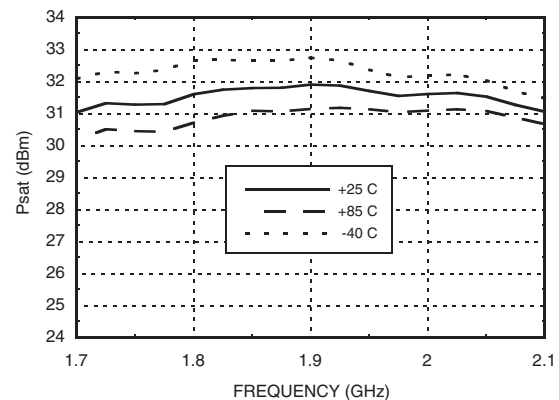
Output Return Loss vs. Temperature @ 1900 MHz



P1dB vs. Temperature @ 1900 MHz



Psat vs. Temperature @ 1900 MHz

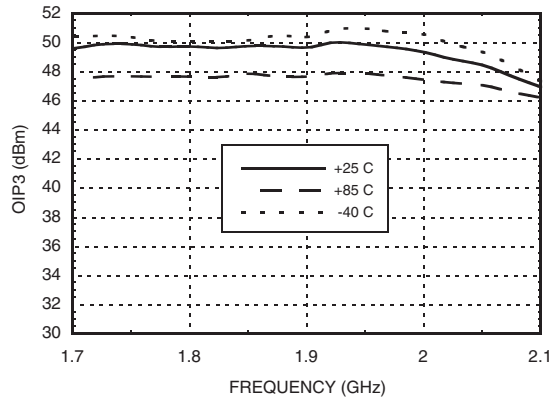




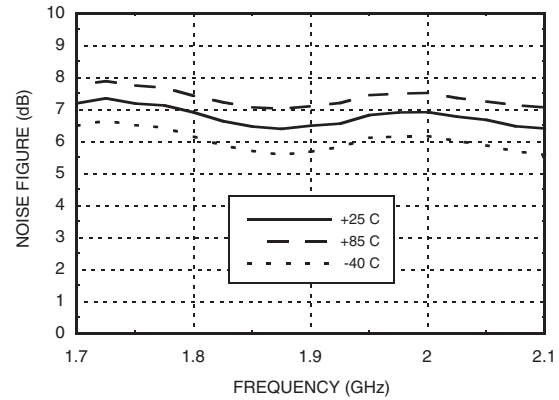
HMC452ST89 / 452ST89E

InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

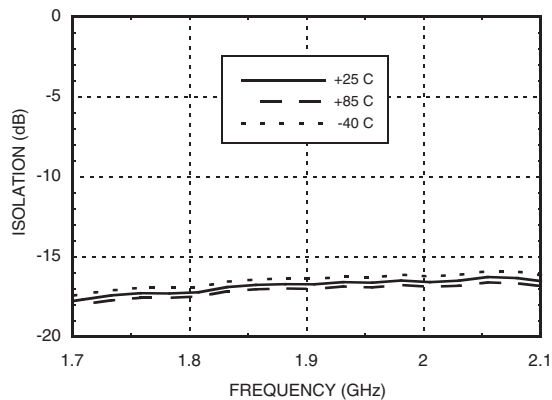
Output IP3 vs. Temperature @ 1900 MHz



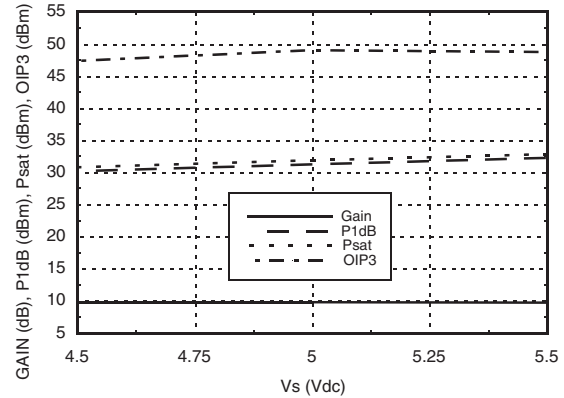
**Noise Figure
vs. Temperature @ 1900 MHz**



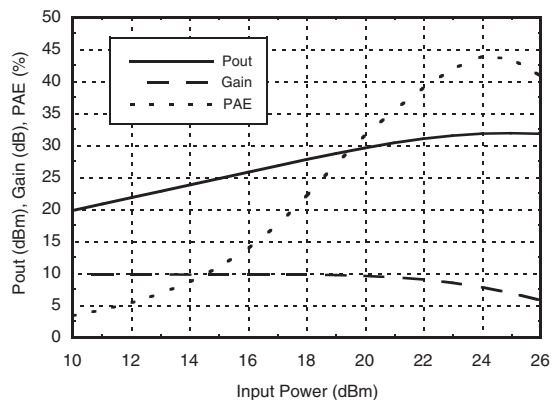
**Reverse Isolation
vs. Temperature @ 1900 MHz**



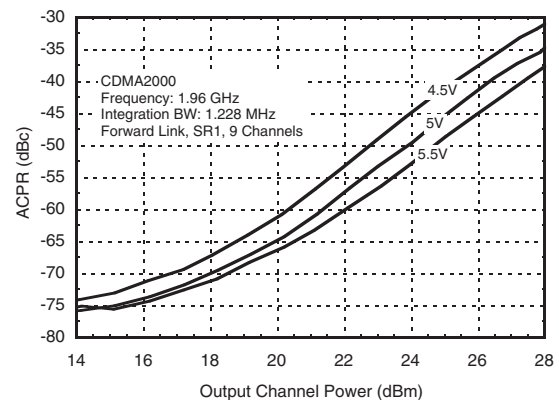
**Gain, Power & IP3
vs. Supply Voltage @ 1900 MHz**



Power Compression @ 1900 MHz



**ACPR vs. Supply Voltage @ 1960 MHz
CDMA 2000, 9 Channels Forward**

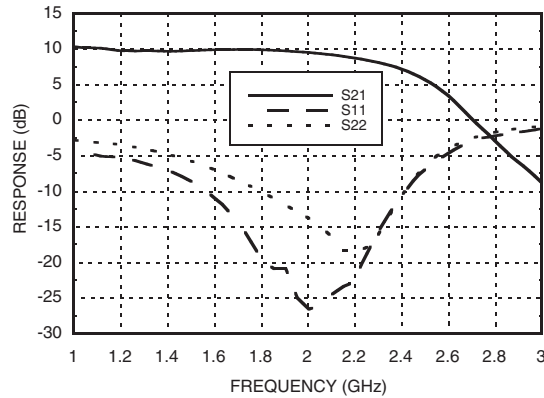




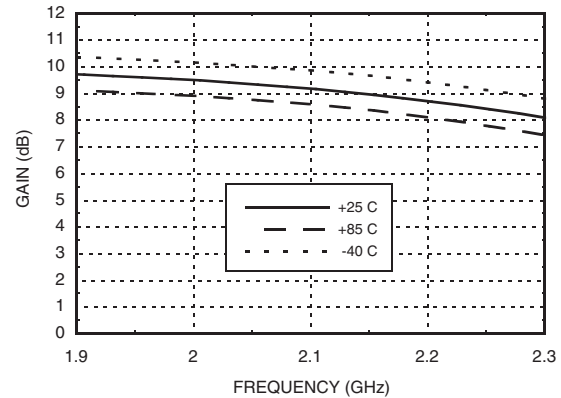
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InGaP HBT 1 WATT POWER AMPLIFIER, 0.4 - 2.2 GHz

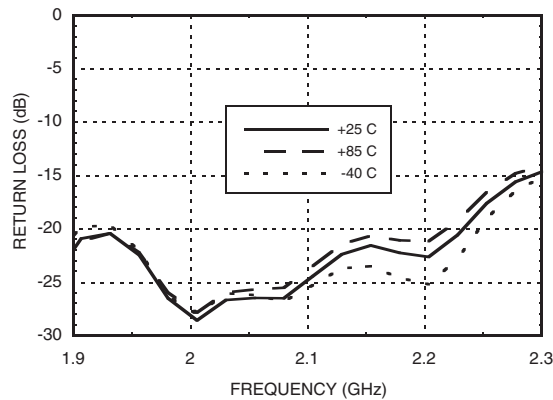
Broadband Gain & Return Loss @ 2100 MHz



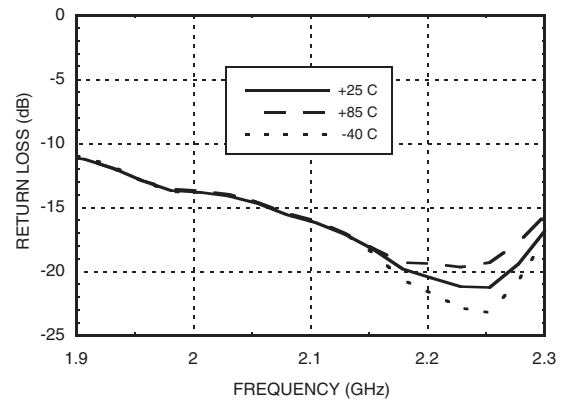
Gain vs. Temperature @ 2100 MHz



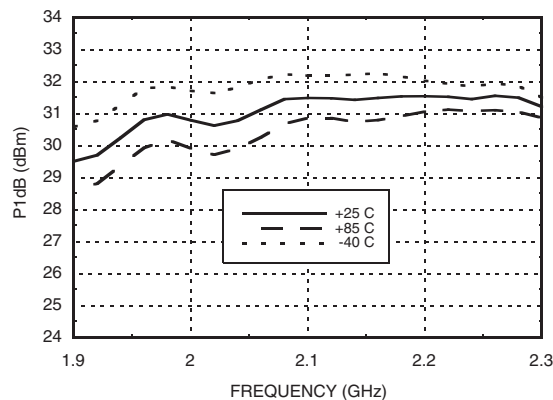
Input Return Loss vs. Temperature @ 2100 MHz



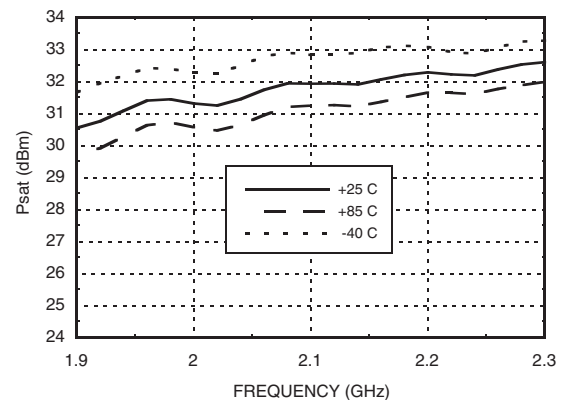
Output Return Loss vs. Temperature @ 2100 MHz



P1dB vs. Temperature @ 2100 MHz



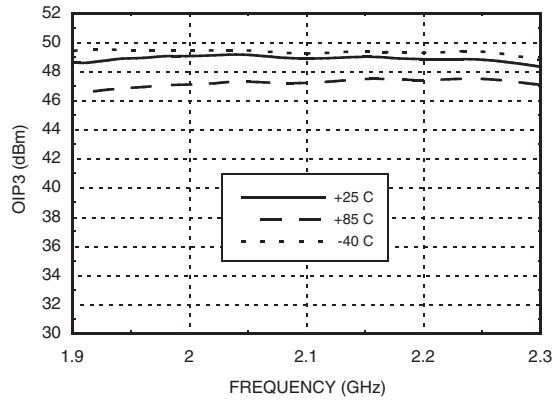
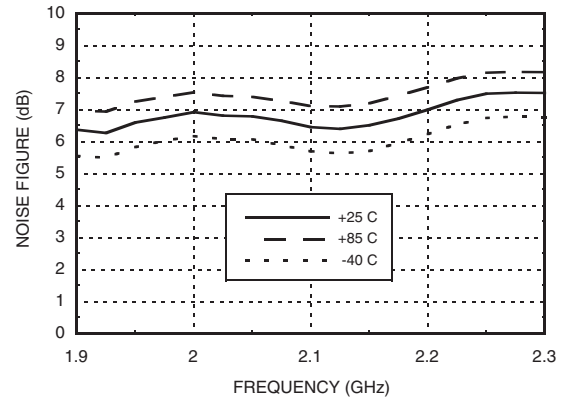
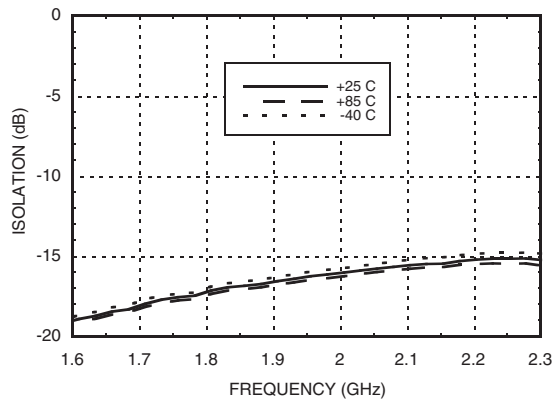
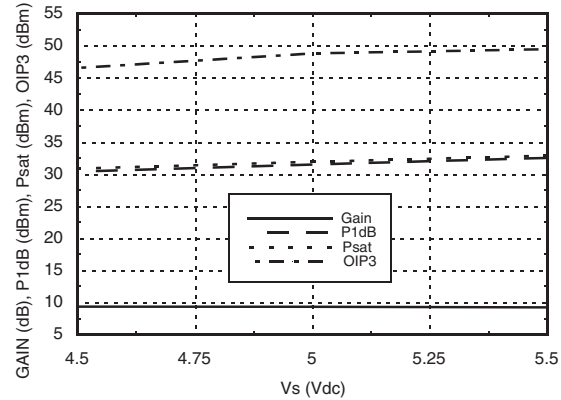
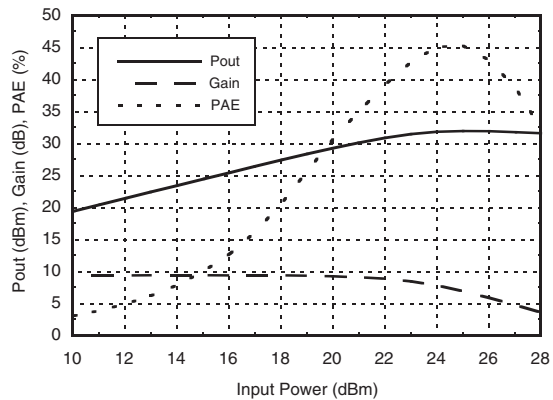
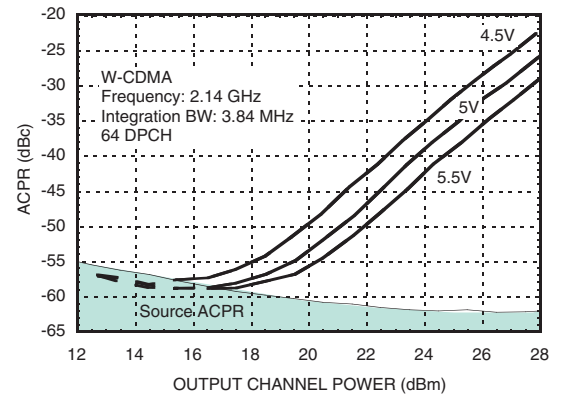
Psat vs. Temperature @ 2100 MHz



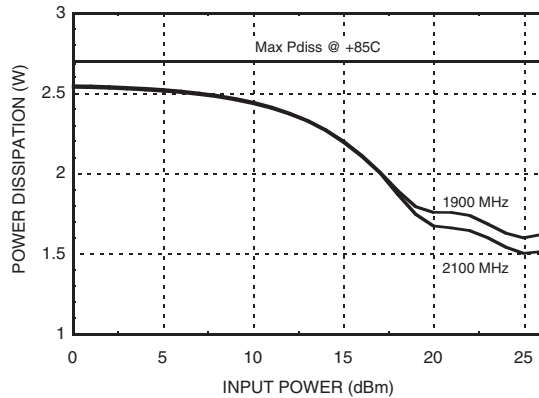


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Output IP3 vs. Temperature @ 2100 MHz

**Noise Figure
vs. Temperature @ 2100 MHz**

**Reverse Isolation
vs. Temperature @ 2100 MHz**

**Gain, Power & IP3
vs. Supply Voltage @ 2100 MHz**

Power Compression @ 2100 MHz

**ACPR vs. Supply Voltage @ 2140 MHz
W-CDMA, 64 DPCH**


Power Dissipation



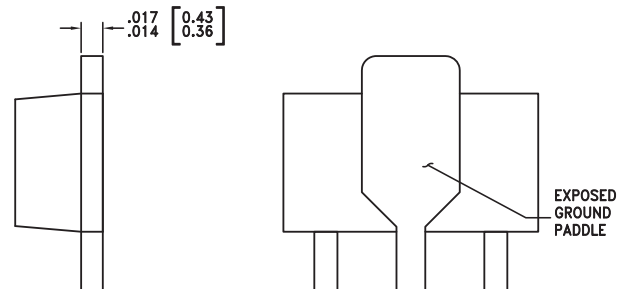
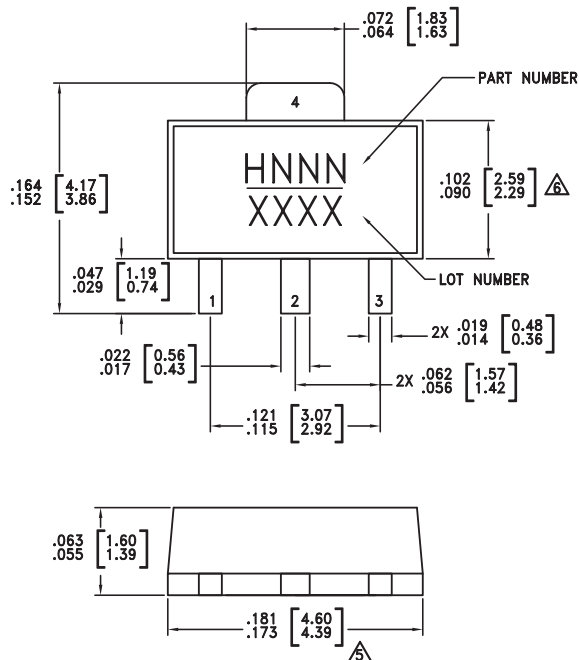
Absolute Maximum Ratings

Collector Bias Voltage (Vcc)	+6.0 Vdc
RF Input Power (RFIN)(Vs +5Vdc)	+31 dBm
Junction Temperature	150 °C
Continuous Pdis (T = 85 °C) (derate 41.5 mW/°C above 85 °C)	2.7 W
Thermal Resistance (junction to ground paddle)	24.1 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing



NOTES:

1. PACKAGE BODY MATERIAL:
MOLDING COMPOUND MP-180S OR EQUIVALENT.
2. LEAD MATERIAL: Cu w/ Ag SPOT PLATING.
3. LEAD PLATING: 100% MATTE TIN.
4. DIMENSIONS ARE IN INCHES [MILLIMETERS]
5. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
6. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
7. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC452ST89	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H452 XXXX
HMC452ST89E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H452 XXXX

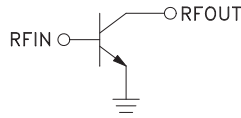
[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

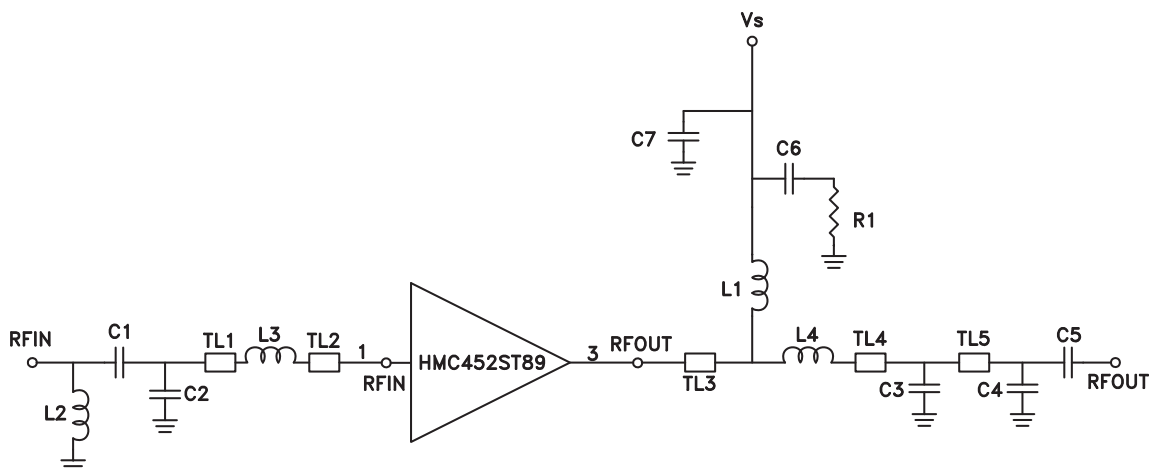


Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN	This pin is DC coupled. Off chip matching components are required. See Application Circuit herein.	
3	RFOUT	RF output and DC Bias input for the output amplifier stage. Off chip matching components are required. See Application Circuit herein.	
2, 4	GND	These pins & package bottom must be connected to RF/DC ground.	

400 MHz Application Circuit

This circuit was used to specify the performance for 400-410 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.

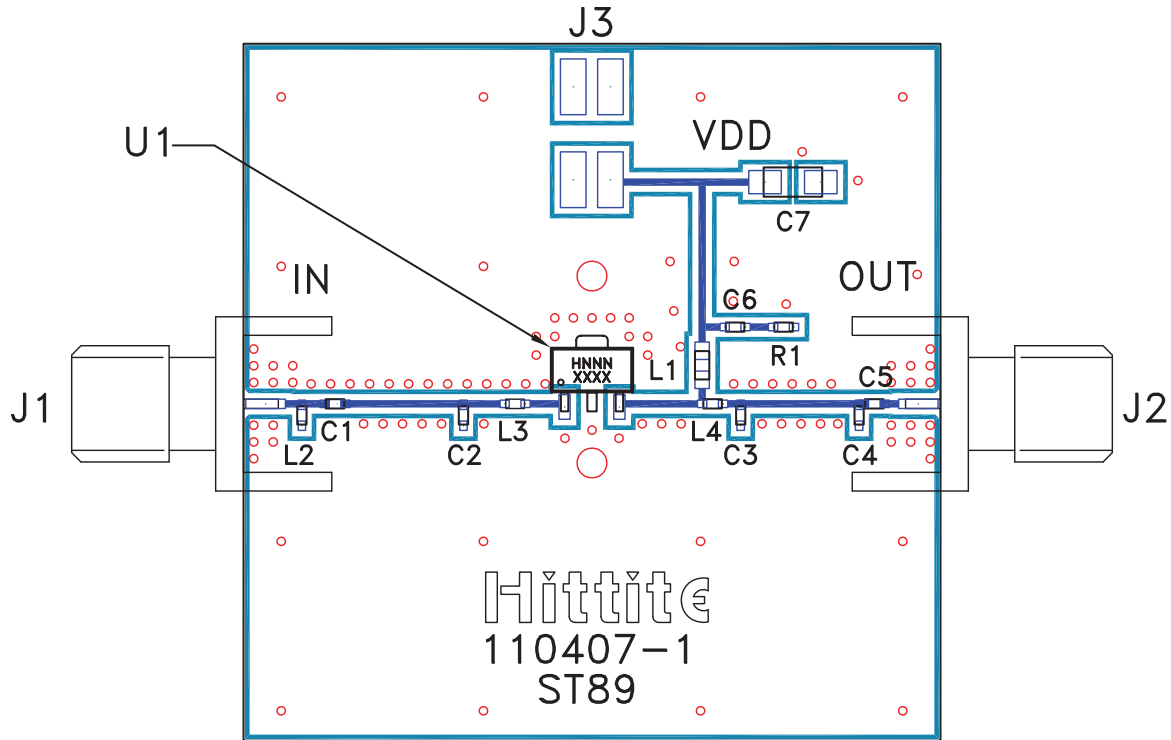


Note: C2 should be placed as close to pins as possible.

	TL1	TL2	TL3	TL4	TL5
Impedance	50 Ohm	50 Ohm	50 Ohm	50 Ohm	50 Ohm
Physical Length	0.09"	0.08"	0.17"	0.04"	0.25"
Electrical Length	2°	2°	4°	1°	6°
PCB Material: 10 mil Rogers 4350, Er = 3.48					

Recommended Component Values	
C1	12 pF
C2	15 pF
C3, C4	6.8 pF
C5	39 pF
C6	100 pF
C7	2.2 μ F
L1	47 nH
L2	40 nH
L3	4.3 nH
L4	5.1 nH
R1	5.1 Ohm

400 MHz Evaluation PCB



List of Materials for Evaluation PCB 110409-400 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	2 mm DC Header
C1	12 pF Capacitor, 0402 Pkg.
C2	15 pF Capacitor, 0402 Pkg.
C3, C4	6.8 pF Capacitor, 0402 Pkg.
C5	39 pF Capacitor, 0402 Pkg.
C6	100 pF Capacitor, 0402 Pkg.
C7	2.2 μ F Capacitor, Tantalum
L1	47 nH Inductor, 0603 Pkg.
L2	40 nH Inductor, 0402 Pkg.
L3	4.3 nH Inductor, 0402 Pkg.
L4	5.1 nH Inductor, 0402 Pkg.
R1	5.1 Ohm Resistor, 0402 Pkg.
U1	HMC452ST89 / HMC452ST89E Linear Amp
PCB [2]	110407 Evaluation PCB, 10 mils

[1] Reference this number when ordering complete evaluation PCB

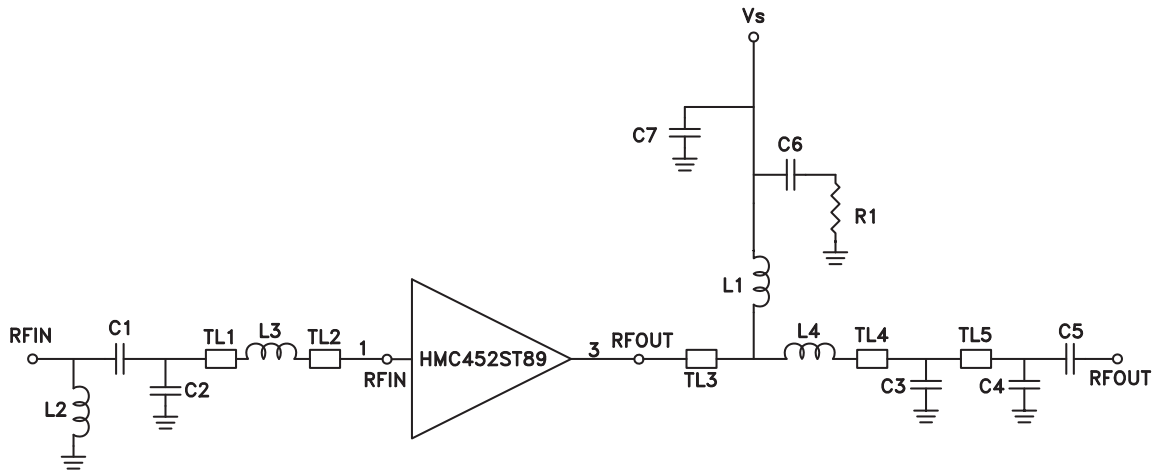
[2] Circuit Board Material: Rogers 4350, Er = 3.48

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.



470 MHz Application Circuit

This circuit was used to specify the performance for 450-496 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



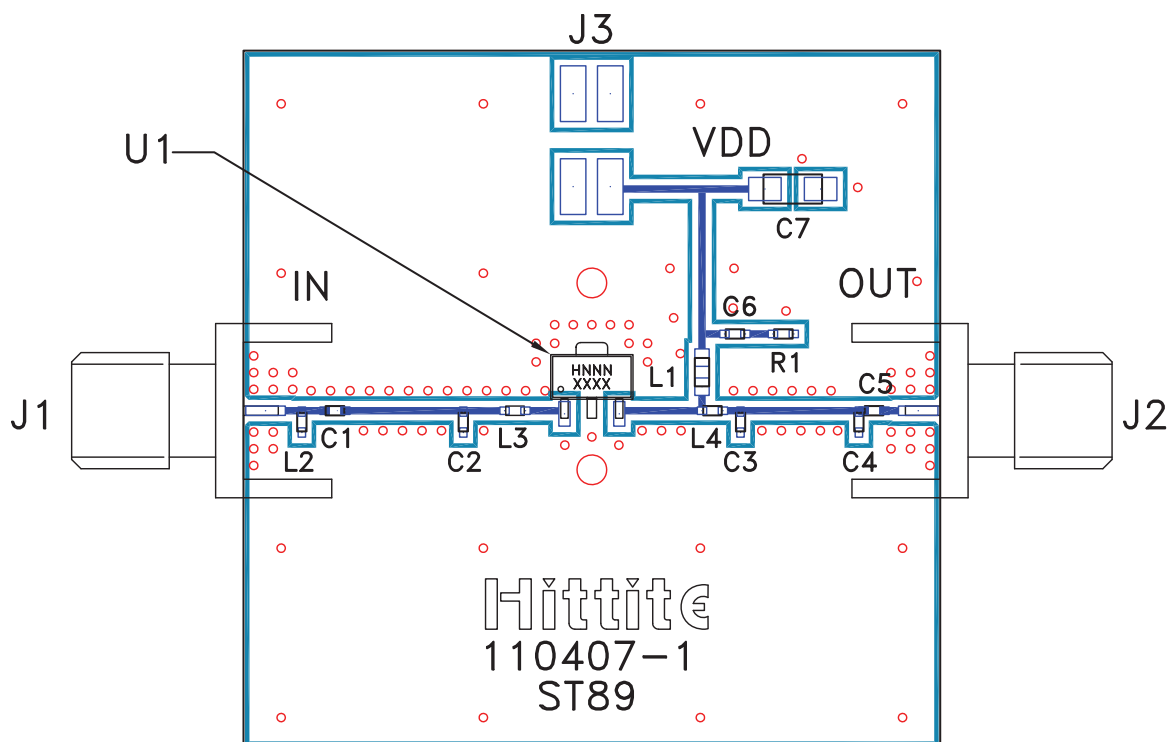
Note: C2 should be placed as close to pins as possible.

	TL1	TL2	TL3	TL4	TL5
Impedance	50 Ohm	50 Ohm	50 Ohm	50 Ohm	50 Ohm
Physical Length	0.09"	0.08"	0.17"	0.04"	0.25"
Electrical Length	2.5°	2°	5°	1°	7°
PCB Material: 10 mil Rogers 4350, Er = 3.48					

Recommended Component Values	
C1, C2	12 pF
C3	6.8 pF
C4	5.6 pF
C5	39 pF
C6	100 pF
C7	2.2 μ F
L1	47 nH
L2	40 nH
L3	4.7 nH
L4	3.9 nH
R1	5.1 Ohm



470 MHz Evaluation PCB



List of Materials for Evaluation PCB 110416-470 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	2 mm DC Header
C1, C2	12 pF Capacitor, 0402 Pkg.
C3	6.8 pF Capacitor, 0402 Pkg.
C4	5.6 pF Capacitor, 0402 Pkg.
C5	39 pF Capacitor, 0402 Pkg.
C6	100 pF Capacitor, 0402 Pkg.
C7	2.2 μ F Capacitor, Tantalum
L1	47 nH Inductor, 0603 Pkg.
L2	40 nH Inductor, 0402 Pkg.
L3	4.7 nH Inductor, 0402 Pkg.
L4	3.9 nH Inductor, 0402 Pkg.
R1	5.1 Ohm Resistor, 0402 Pkg.
U1	HMC452ST89 / HMC452ST89E Linear Amp
PCB [2]	110407 Evaluation PCB, 10 mils

[1] Reference this number when ordering complete evaluation PCB

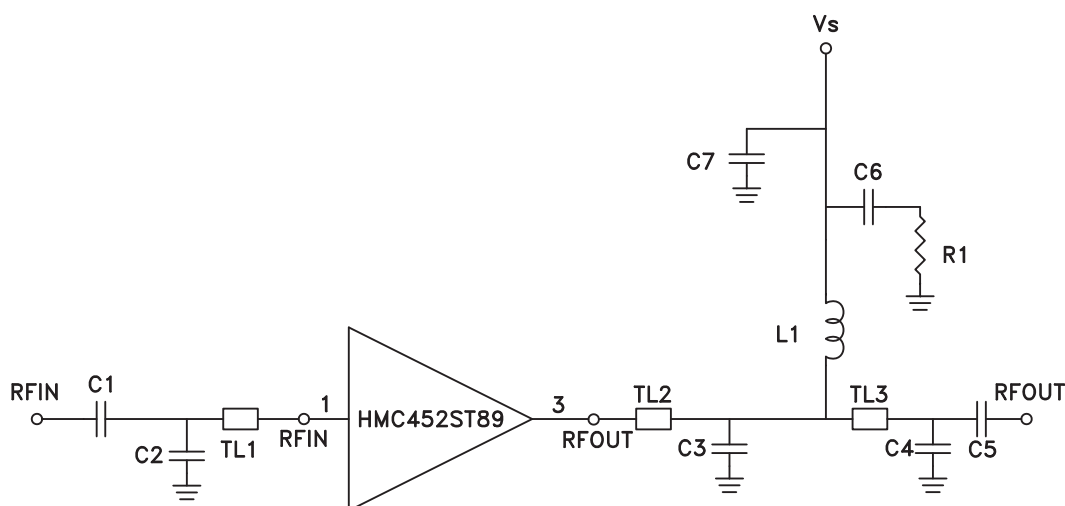
[2] Circuit Board Material: Rogers 4350, Er = 3.48

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.



900 MHz Application Circuit

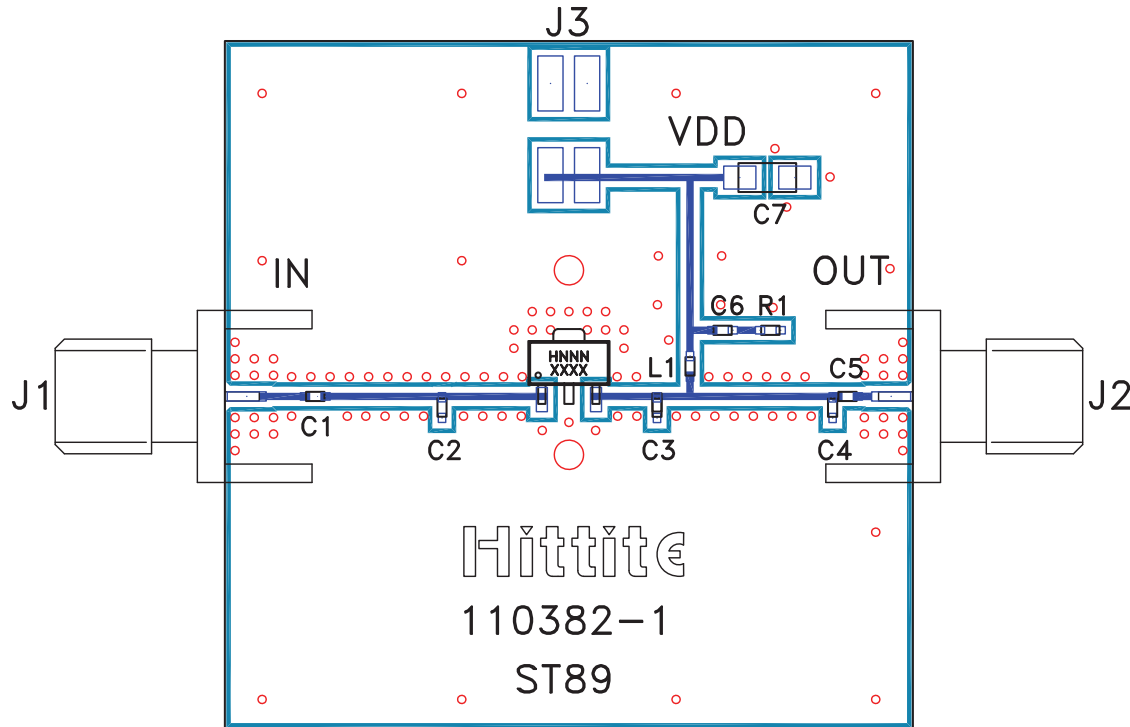
This circuit was used to specify the performance for 810-960 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



Note: C2 should be placed as close to pins as possible.

	TL1	TL2	TL3
Impedance	50 Ohm	50 Ohm	50 Ohm
Physical Length	0.21"	0.13"	0.38"
Electrical Length	11°	7°	20°
PCB Material: 10 mil Rogers 4350, Er = 3.48			

Recommended Component Values	
C1	27 pF
C2	6.8 pF
C3	2.2 pF
C4	4.7 pF
C5	5.6 pF
C6	100 pF
C7	2.2 μF
L1	20 nH
R1	5.1 Ohm


900 MHz Evaluation PCB

List of Materials for Evaluation PCB 110384-900 ^[1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	2 mm DC Header
C1	27 pF Capacitor, 0402 Pkg.
C2	6.8 pF Capacitor, 0402 Pkg.
C3	2.2 pF Capacitor, 0402 Pkg.
C4	4.7 pF Capacitor, 0402 Pkg.
C5	5.6 pF Capacitor, 0402 Pkg.
C6	100 pF Capacitor, 0402 Pkg.
C7	2.2 μ F Capacitor, Tantalum
L1	20 nH Inductor, 0402 Pkg.
R1	5.1 Ohm Resistor, 0402 Pkg.
U1	HMC452ST89 / HMC452ST89E Linear Amp
PCB ^[2]	110382 Evaluation PCB, 10 mils

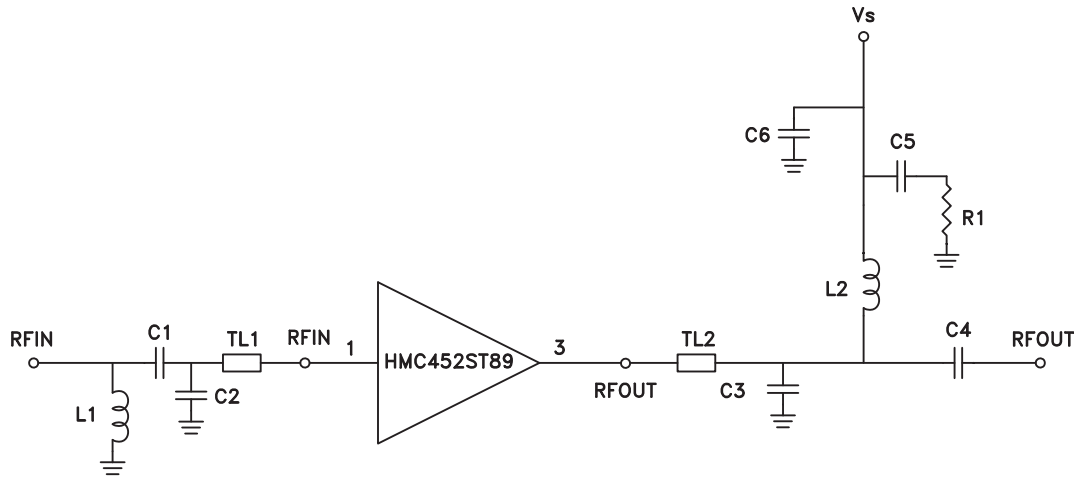
[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

1900 MHz Application Circuit

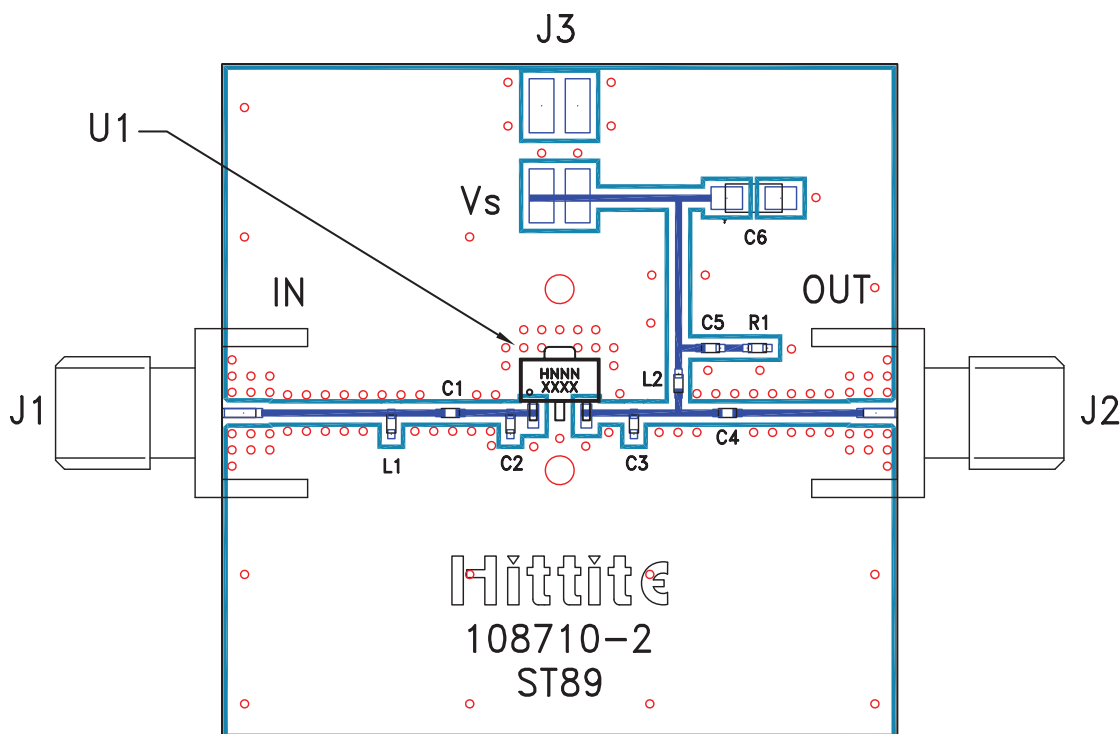
This circuit was used to specify the performance for 1710-1990 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



Note: C2 should be placed as close to pins as possible.

	TL1	TL2
Impedance	50 Ohm	50 Ohm
Physical Length	0.04"	0.10"
Electrical Length	4°	11°
PCB Material: 10 mil Rogers 4350, Er = 3.48		

Recommended Component Values	
C1	3 pF
C2	2 pF
C3	3.3 pF
C4	15 pF
C5	100 pF
C6	2.2 μF
L1	10 nH
L2	12 nH
R1	5.1 Ohm


1900 MHz Evaluation PCB

List of Materials for Evaluation PCB 108712-1900 ^[1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	2 mm DC Header
C1	3 pF Capacitor, 0402 Pkg.
C2	2 pF Capacitor, 0402 Pkg.
C3	3.3 pF Capacitor, 0402 Pkg.
C4	15 pF Capacitor, 0402 Pkg.
C5	100 pF Capacitor, 0402 Pkg.
C6	2.2 μ F Capacitor, Tantalum
L1	10 nH Inductor, 0402 Pkg.
L2	12 nH Inductor, 0402 Pkg.
R1	5.1 Ohm Resistor, 0402 Pkg.
U1	HMC452ST89 / HMC452ST89E Linear Amp
PCB ^[2]	108710 Evaluation PCB, 10 mils

[1] Reference this number when ordering complete evaluation PCB

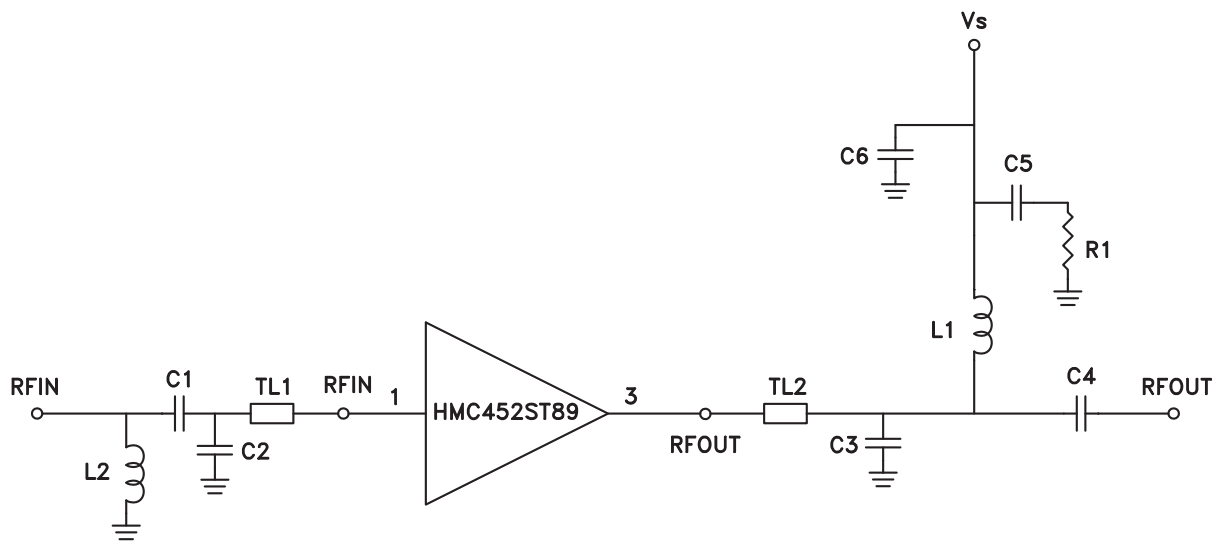
[2] Circuit Board Material: Rogers 4350, Er = 3.48

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.



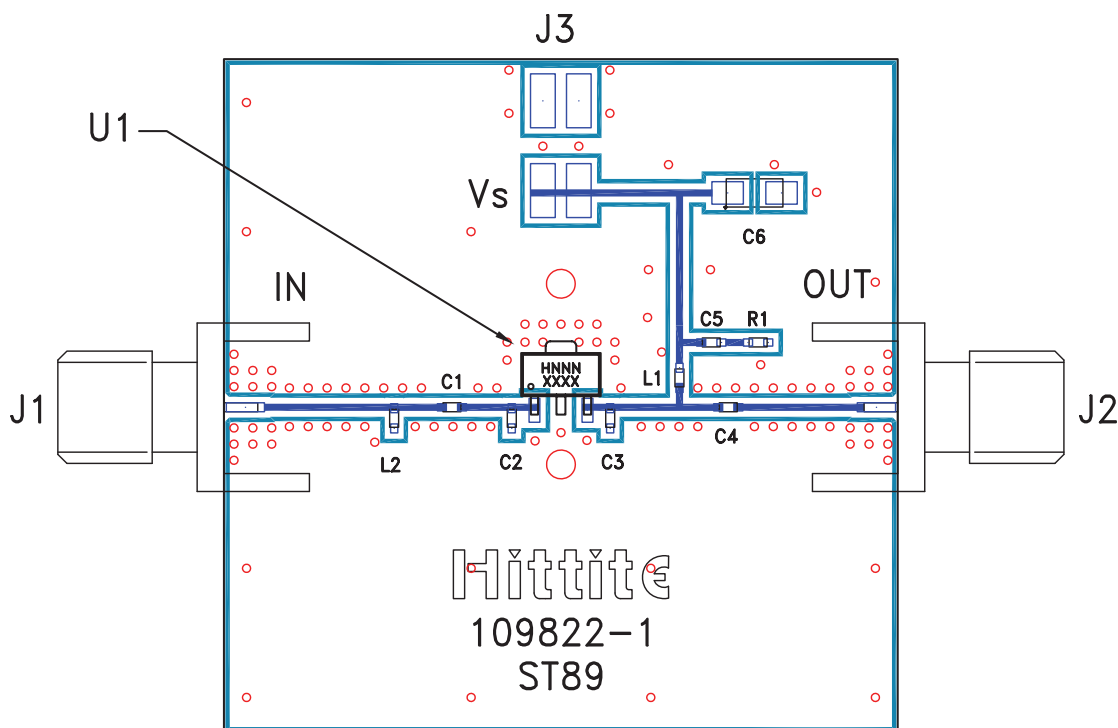
2100 MHz Application Circuit

This circuit was used to specify the performance for 2010-2170 MHz operation. Contact the HMC Applications Group for assistance in optimizing performance for your application.



	TL1	TL2
Impedance	50 Ohm	50 Ohm
Physical Length	0.04"	0.04"
Electrical Length	5°	5°
PCB Material: 10 mil Rogers 4350, Er = 3.48		

Recommended Component Values	
C1	3 pF
C2	2 pF
C3	3.3 pF
C4	15 pF
C5	100 pF
C6	2.2 μ F
L1	12 nH
L2	10 nH
R1	5.1 Ohm


2100 MHz Evaluation PCB

List of Materials for Evaluation PCB 109824-2100 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	2 mm DC Header
C1	3 pF Capacitor, 0402 Pkg.
C2	2 pF Capacitor, 0402 Pkg.
C3	3.3 pF Capacitor, 0402 Pkg.
C4	15 pF Capacitor, 0402 Pkg.
C5	100 pF Capacitor, 0402 Pkg.
C6	2.2 μ F Capacitor, Tantalum
L1	12 nH Inductor, 0402 Pkg.
L2	10 nH Inductor, 0402 Pkg.
R1	5.1 Ohm Resistor, 0402 Pkg.
U1	HMC452ST89 / HMC452ST89E Linear Amp
PCB [2]	109822 Evaluation PCB, 10 mils

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350, Er = 3.48

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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